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## S20C45K

#### **Schottky Barrier Rectifiers** SCHOTTKY BARRIER Using the Schottky Barrier principle with a Molybdenum barrier RECTIFIERS metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low **20 AMPERES** voltage, high frequency rectification, or as free wheeling and polarity 45 VOLTS protection diodes. Features \*Low Forward Voltage. \*Low Switching noise. \* High Current Capacity \* Guarantee Reverse Avalanche. \* Guard-Ring for Stress Protection. \*Low Power Loss & High efficiency. \*150°C Operating Junction Temperature \* Low Stored Charge Majority Carrier Conduction. \* Plastic Material used Carries Underwriters Laboratory **TO-220AB** \*ESD: 8KV(Min.) Human-Body Model \* Flammability Classification 94V-O \* Pb free \* In compliance with EU RoHs directives **MAXIMUM RATINGS** Characteristic Symbol S20C45K Unit Peak Repetitive Reverse Voltage $V_{RRM}$ Working Peak Reverse Voltage 45 V V<sub>RWM</sub> **DC Blocking Voltage** $V_R$ V<sub>R(RMS)</sub> 32 V **RMS Reverse Voltage** Average Rectifier Forward Current (per diode) 10 А I<sub>F(AV)</sub> Total Device (Rated V<sub>R</sub>), T<sub>C</sub>=100°C 20 Peak Repetitive Forward Current 20 А I<sub>FM</sub> (Rate V<sub>R</sub>, Square Wave, 20kHz) Non-Repetitive Peak Surge Current (Surge applied at rate 150 IFSM А load conditions halfware, single phase, 60Hz) -65 to +150 Operating and Storage Junction Temperature Range T<sub>J</sub>, T<sub>stq</sub> °C ELECTRICAL CHARACTERISTICS Characteristic Symbol S20C45K Unit Maximum Instantaneous Forward Voltage ( I<sub>F</sub> =10 Amp T<sub>C</sub> = 25℃) Case $V_{F}$ 0.60 V ( I<sub>F</sub> =10Amp T<sub>C</sub> = 100°C) 0.52 Typical Thermal Resistance junction to case (per device) 3.8 °C/w R<sub>θ i-c</sub> Maximum Instantaneous Reverse Current

 $I_R$ 

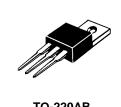
0.1

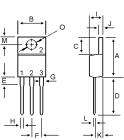
20

mΑ

(Rated DC Voltage, T<sub>C</sub> = 25°C)

(Rated DC Voltage, T<sub>C</sub> = 125°C)

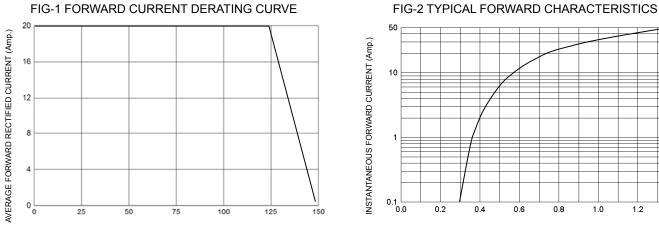




DIM	MILLIMETERS	
	MIN	MAX
Α	14.68	16.00
В	9.78	10.42
С	5.02	6.60
D	13.00	14.62
Е	3.10	4.19
F	2.41	2.67
G	1.10	1.67
н	0.69	1.01
I	3.21	4.98
J	1.14	1.40
К	2.20	3.30
L	0.28	0.61
М	2.48	3.00
0	3.50	4.00



## S20C45K

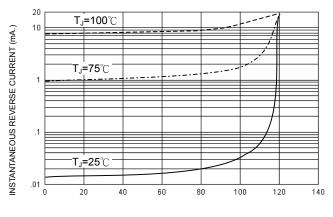


CASE TEMPERATURE (°C)

0.6 0.8 1.0 1.2 1.4

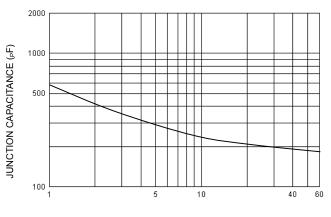
FORWARD VOLTAGE (Volts)

FIG-3 TYPICAL REVERSE CHARACTERISTICS

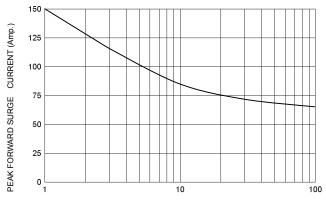


PERCENT OF RATED REVERSE VOLTAGE (%)

FIG-4 TYPICAL JUNCTION CAPACITANCE



**REVERSE VOLTAGE (Volts)** 



NUMBER OF CYCLES AT 60 Hz

FIG-5 PEAK FORWARD SURGE CURRENT



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